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No



View Online at https://aerobasegroup.com/nsn/5961-01-235-8888

Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.750 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Unijunction
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-18
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case and quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 gate voltage, dc
Current Rating Per Characteristic:
5.00 amperes forward current, average preset
Power Rating Per Characteristic:
0.3 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/493 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

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